



# PJD10N10

## 100V N-Channel MOSFET

**Voltage**

**100 V**

**Current**

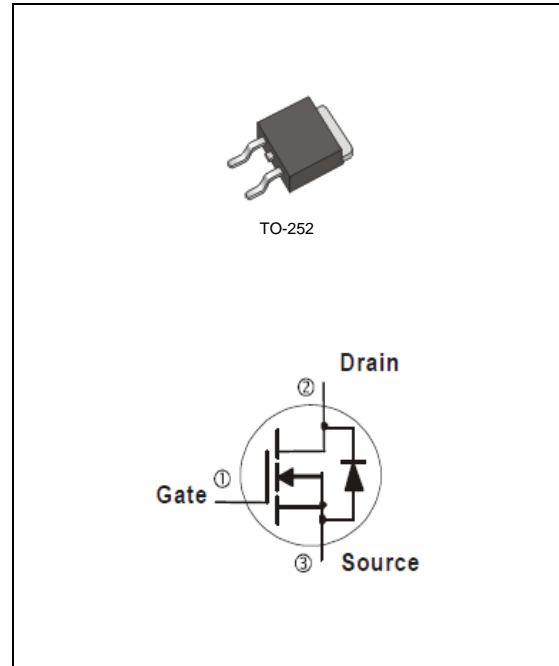
**10 A**

### Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@5A < 130m\Omega$
- $R_{DS(ON)}, V_{GS}@6V, I_D@2A < 135m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case : TO-252 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	100	V
Gate-Source Voltage		$V_{GS}$	$\pm 25$	V
Continuous Drain Current	$T_C=25^\circ\text{C}$	$I_D$	10	A
	$T_C=100^\circ\text{C}$		6.5	
Pulsed Drain Current (Note 1)	$T_C=25^\circ\text{C}$	$I_{DM}$	40	
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	34.7	W
	$T_C=100^\circ\text{C}$		14	
Continuous Drain Current	$T_A=25^\circ\text{C}$	$I_D$	2.6	A
	$T_A=70^\circ\text{C}$		2.1	A
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2.0	W
Power Dissipation	$T_A=70^\circ\text{C}$		1.3	
Single Pulse Avalanche Energy (Note 6)		$E_{AS}$	6	mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	3.6	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	100	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2.0	2.76	3.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=5A$	-	110	130	m $\Omega$
		$V_{GS}=6V, I_D=2A$	-	120	135	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=100V, V_{GS}=0V$	-	0.01	1.0	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	$\pm 20$	$\pm 100$	nA
<b>Dynamic</b> (Note 7)						
Total Gate Charge	$Q_g$	$V_{DS}=37.5V, I_D=5A,$ $V_{GS}=10V$ (Note 2,3)	-	12	-	nC
Gate-Source Charge	$Q_{gs}$		-	3.1	-	
Gate-Drain Charge	$Q_{gd}$		-	2.2	-	
Input Capacitance	$C_{iss}$	$V_{DS}=30V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	707	-	pF
Output Capacitance	$C_{oss}$		-	40	-	
Reverse Transfer Capacitance	$C_{rss}$		-	16	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=37.5V, R_L=7.5\Omega,$ $V_{GS}=10V, R_G=3\Omega$ (Note 2,3)	-	6	-	ns
Turn-On Rise Time	$t_r$		-	27	-	
Turn-Off Delay Time	$t_{d(off)}$		-	15	-	
Turn-Off Fall Time	$t_f$		-	7	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	10	A
Diode Forward Voltage	$V_{SD}$	$I_S=1A, V_{GS}=0V$	-	0.76	1.0	V

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics
3. Repetitive rating, pulse width limited by junction temperature  $T_J(\text{MAX})=150^\circ\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ\text{C}$ .
4. The maximum current rating is package limited
5.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz. square pad of copper.
6. The test condition is  $L=0.1\text{mH}$ ,  $I_{AS}=11A$ ,  $V_{DD}=25V$ ,  $V_{GS}=10V$
7. Guaranteed by design, not subject to production testing



# PJD10N10

## TYPICAL CHARACTERISTIC CURVES

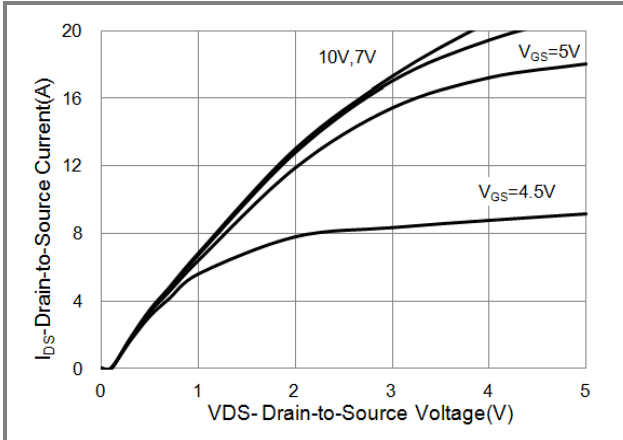


Fig.1 On-Region Characteristics

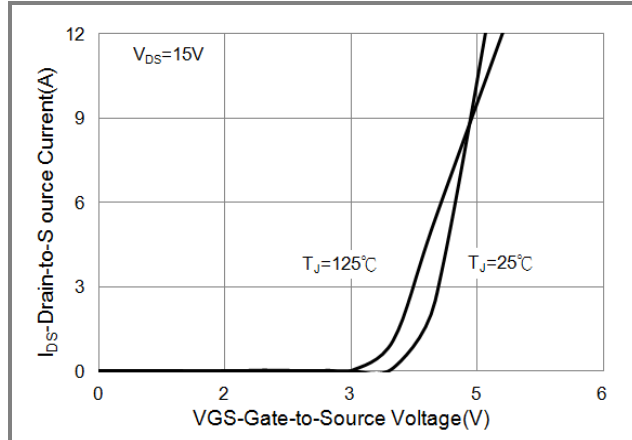


Fig.2 Transfer Characteristics

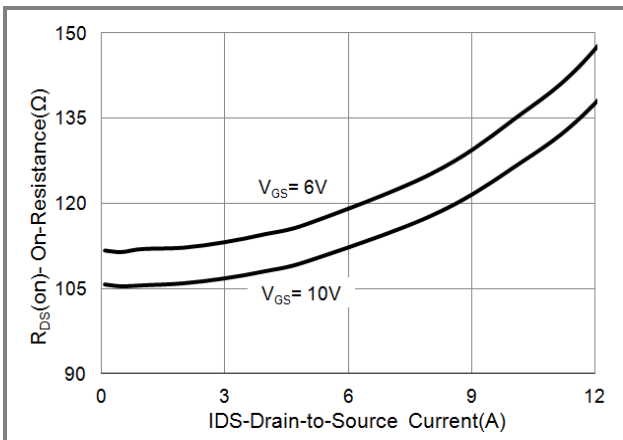


Fig.3 On-Resistance vs. Drain Current

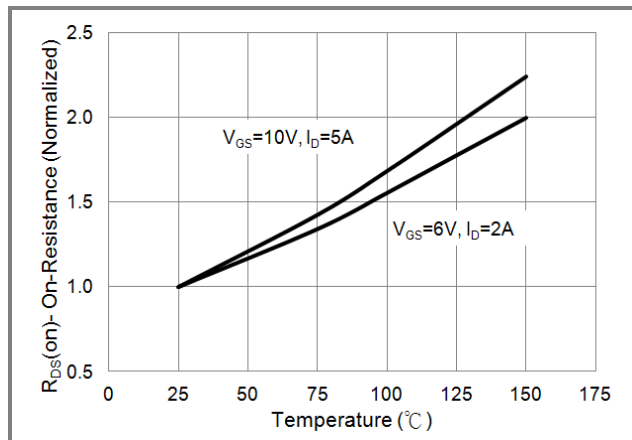


Fig.4 On-Resistance vs. Junction temperature

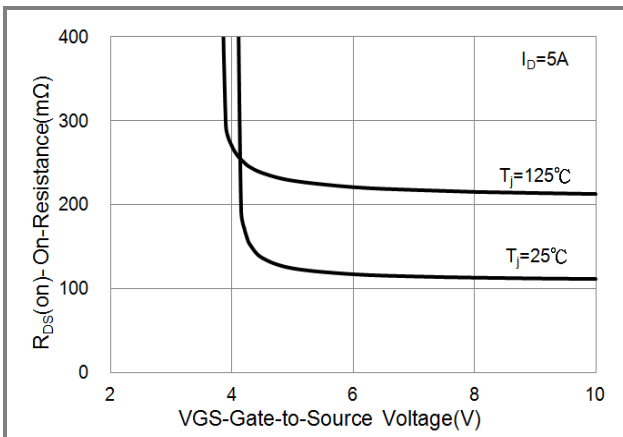


Fig.5 On-Resistance Variation with VGS.

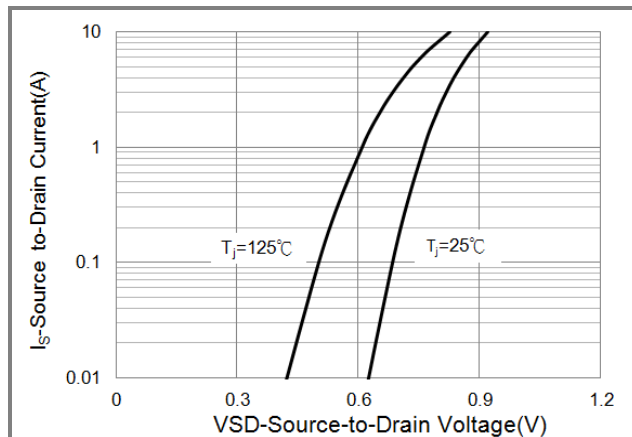
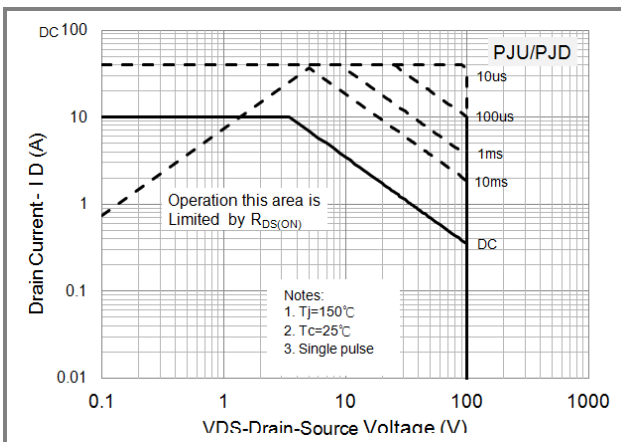
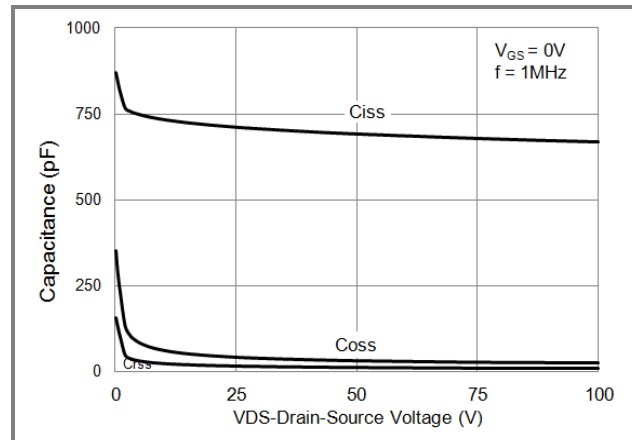
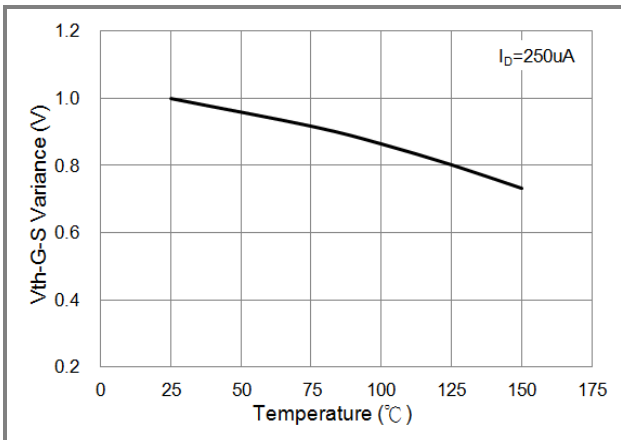
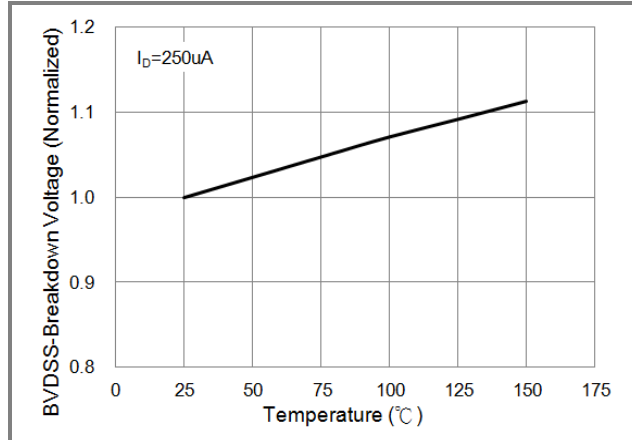
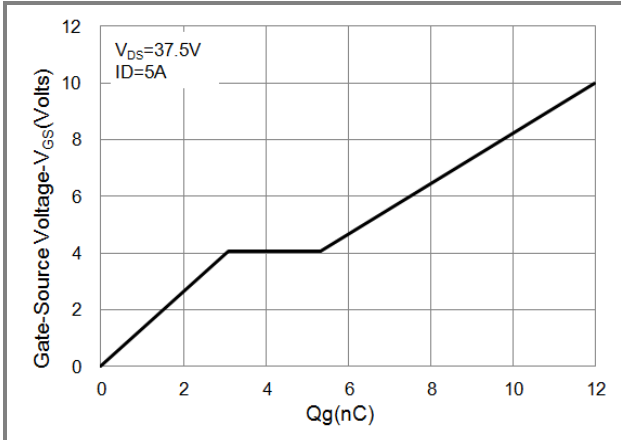


Fig.6 Body Diode Characteristic



# PJD10N10

## TYPICAL CHARACTERISTIC CURVES





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## TYPICAL CHARACTERISTIC CURVES

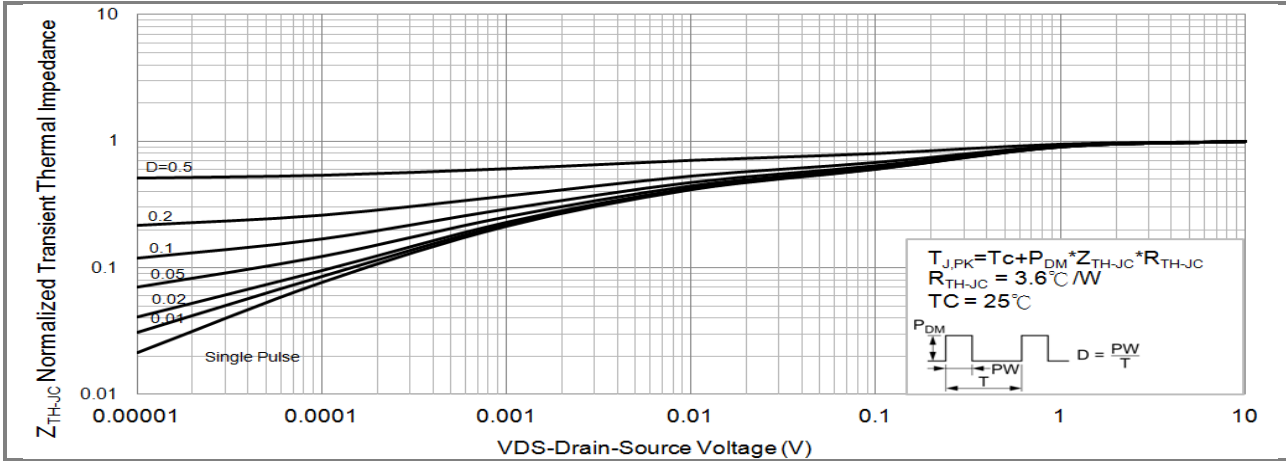
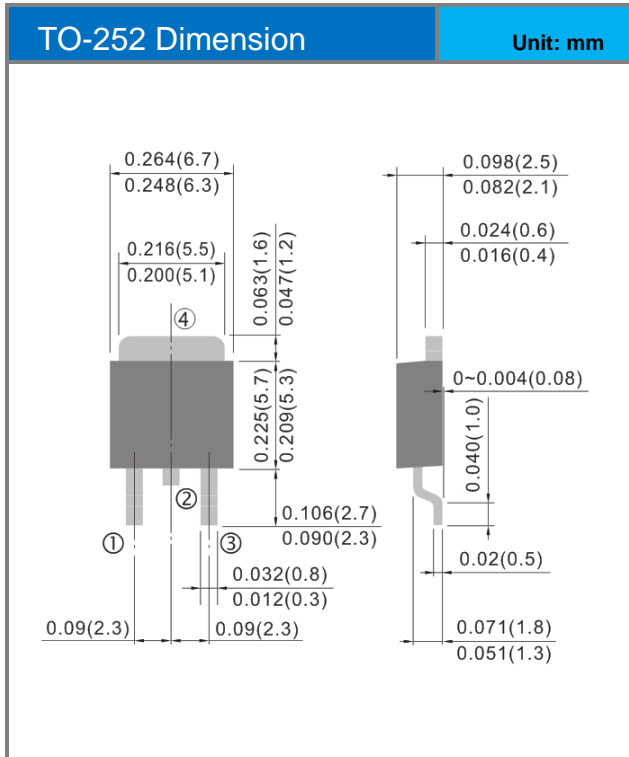


Fig.12 Normalized Thermal Transient Impedance



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## Packaging Information



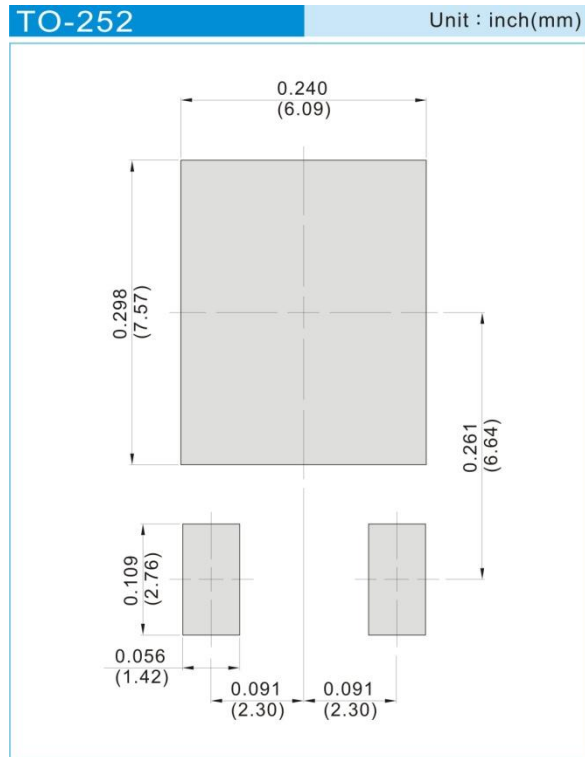


# PJD10N10

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJD10N10_L2_00001	TO-252	3,000pcs / 13" reel	D10N10	Halogen free

## MOUNTING PAD LAYOUT





## PJD10N10

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